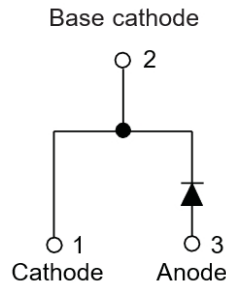


Ultra-Fast Recovery Rectifier Diodes



Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-247AC
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURU7560P
Device marking code			MURU7560P
Repetitive Peak Reverse Voltage	VRRM	V	600
Average Rectified Output Current @60Hz half sine-wave, R-load, T _c (FIG.1)	I _o	A	75
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	IFSM	A	600
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s.	1494
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175
Typical Junction capacitance @4V,1MHz	C _j	pF	290



MURU7560P

■Electrical Characteristics (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
instantaneous forward voltage drop per diode	VFM	V	I _{FM} =75.0A T _j =25°C	-	1.45	1.80
DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	uA	V _{RM} =V _{RRM} T _j =25°C	-	-	10.0
	I _{RRM2}		V _{RM} =V _{RRM} T _j =125°C	-	-	200
Reverse Recovery Time	T _{rr}	ns	I _F =0.5A I _{RM} =1A I _{RR} =0.25A T _j =25°C	-	50	75
			T _j =25°C	-	45	-
			T _j =125°C	-	153	-
Peak recovery current	I _{RRM}	A	T _j =25°C	-	4.78	-
			T _j =125°C	I _F =75A di/dt=-200A/us V _{RM} =400V	-	12.14
Reverse recovery charge	Q _{rr}	nC	T _j =25°C	-	107	-
			T _j =125°C	-	1029	-

■Thermal Characteristics (T_j=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MURU7560P
Thermal Resistance	Between junction and case	R _{θJ-C}	°CW	0.6
	Between junction and Air	R _{θJ-A}	°CW	45

■Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MURU7560P	Approximate 6.0	30	360	1800	Tube

■Characteristics (Typical)

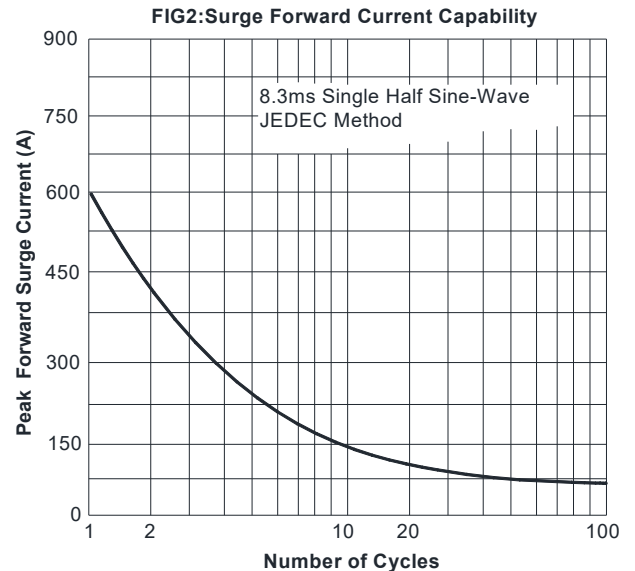
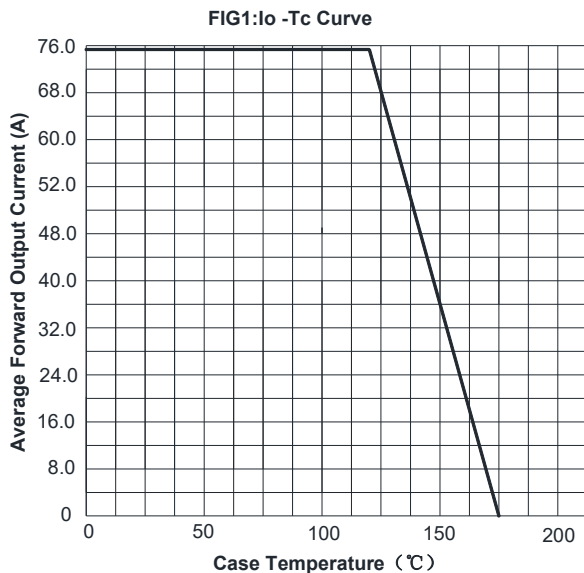


FIG3: Forward Voltage

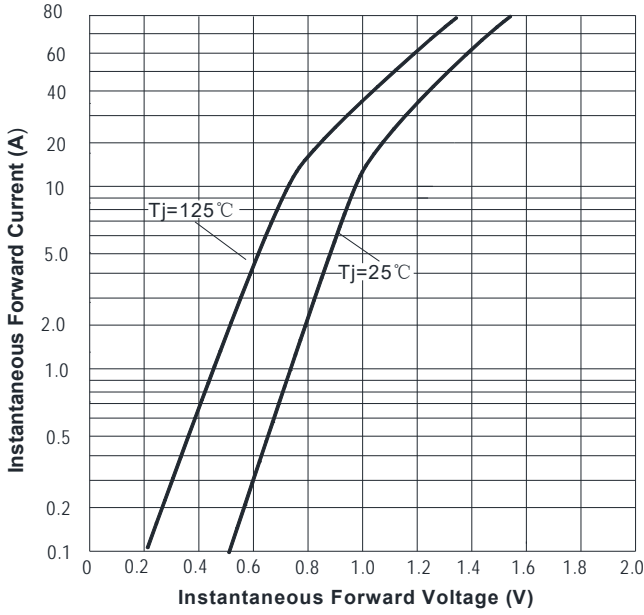


FIG4: Typical Reverse Characteristics

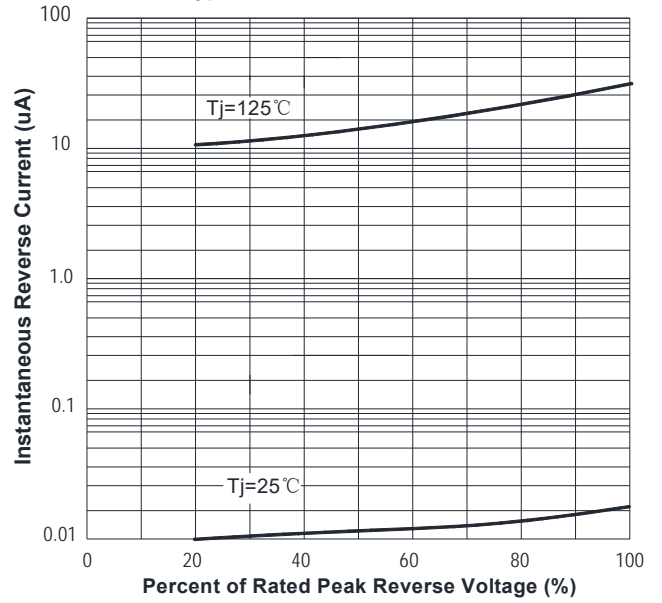
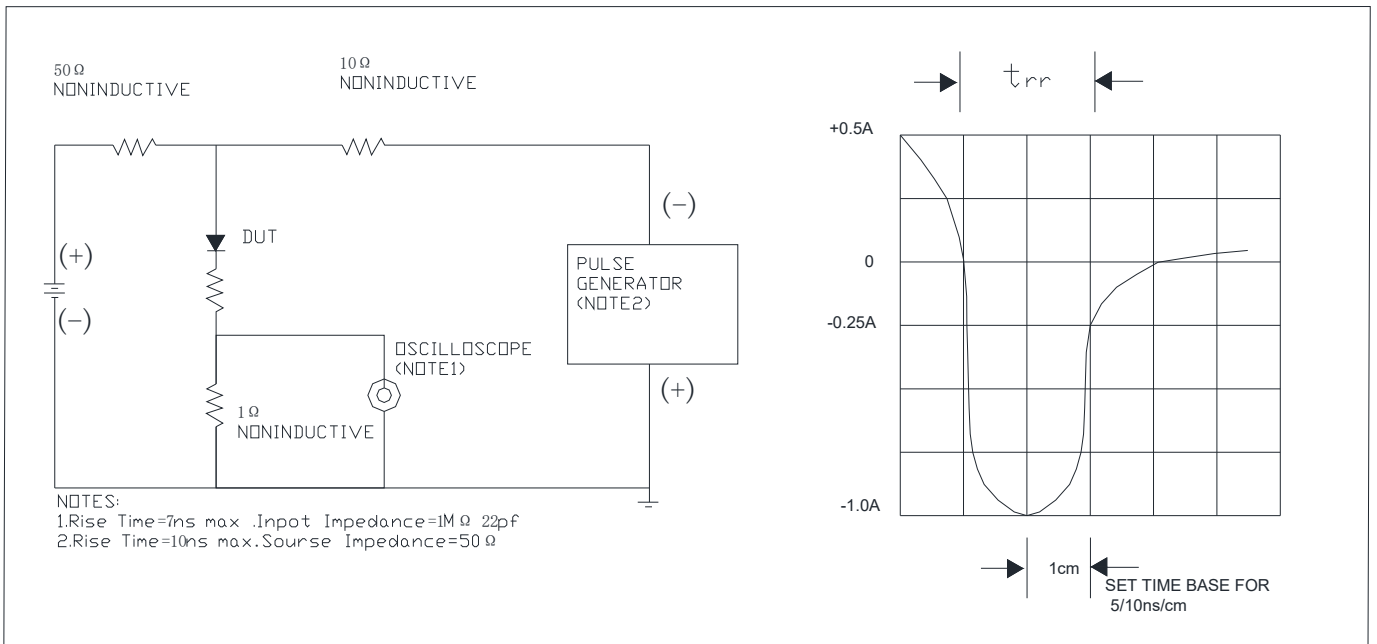


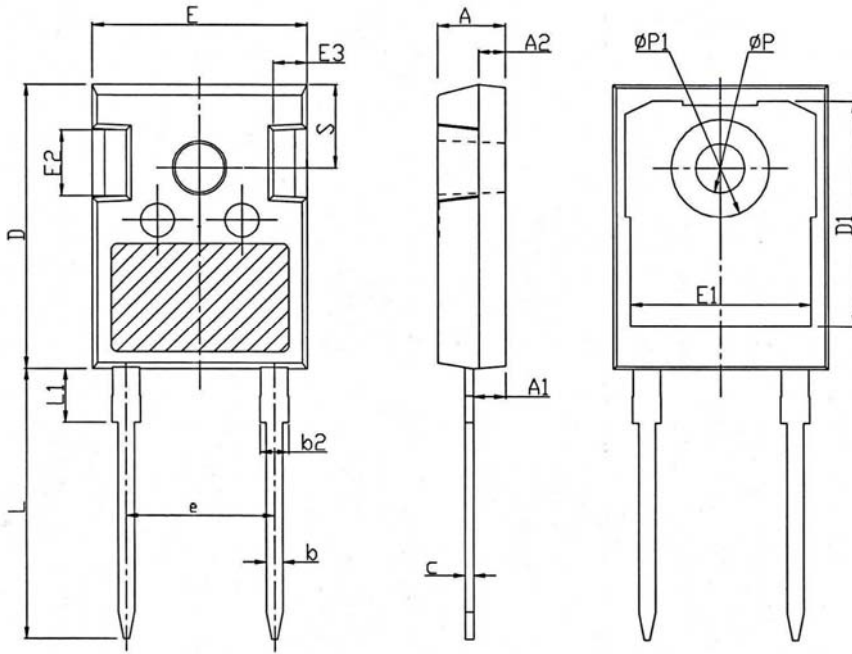
FIG.5 Diagram of circuit and Testing wave form of reverse recovery time





MURU7560P

■Outline Dimensions



TO-247AC		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.11	1.36
b2	1.91	2.21
c	0.51	0.75
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.00	13.60
E2	4.80	5.20
E3	2.30	2.70
e	10.88BSC	
L	19.62	20.22
L1	-	4.30
ϕP	3.40	3.80
$\phi P1$	-	7.30
S	6.15BSC	



MURU7560P

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